

View Online at <https://aerobasegroup.com/nsn/5980-01-203-7234>

General Description:

7nnp silicon planar phototransistor 1; galium arsenide infared emitting diode 1; packaged in a dual in line unit o/a dim. 0.355 in. Max. Lg; 0.270 in. Max. W; 0.175 in. Max. Hgt; teminals printed circuit type 6; operating temp. -55.0 to 100.0 degrees c

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A23900